International AUTON Rectifier

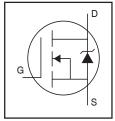
AUTOMOTIVE GRADE

AUIRFR3504

HEXFET® Power MOSFET

Features

- Advanced Planar Technology
- Low On-Resistance
- 175°C Operating Temperature
- Fast Switching
- Fully Avalanche Rated
- Repetitive Avalanche Allowed up to Tjmax
- Lead-Free, RoHS Compliant
- Automotive Qualified*



V _{(BR)DSS}	40V
R _{DS(on)} typ.	7.8m Ω
max	9.2m Ω
I _{D (Silicon Limited)}	87A®
I _D (Package Limited)	56A

Description

Specifically designed for Automotive applications, this Stripe Planar design of HEXFET® Power MOSFETs utilizes the latest processing techniques to achieve low on-resistance per silicon area. This benefit combined with the fast switching speed and ruggedized device design that HEXFET power MOSFETs are well known for, provides the designer with an extremely efficient and reliable device for use in Automotive and a wide variety of other applications.



G	D	S
Gate	Drain	Source

Absolute Maximum Ratings

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only; and functional operation of the device at these or any other condition beyond those indicated in the specifications is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions. Ambient temperature (T_A) is 25°C, unless otherwise specified.

	Parameter	Max.	Units
I _D @ T _C = 25°C	Continuous Drain Current, V _{GS} @ 10V (Silicon Limited)	87®	
I _D @ T _C = 100°C	Continuous Drain Current, VGS @ 10V (Silicon Limited)	61®	Α
I _D @ T _C = 25°C	Continuous Drain Current, V _{GS} @ 10V (Package Limited)	56	
I _{DM}	Pulsed Drain Current ①	350	
P _D @T _C = 25°C	Power Dissipation	140	W
	Linear Derating Factor	0.92	W/°C
V_{GS}	Gate-to-Source Voltage	± 20	V
E _{AS}	Single Pulse Avalanche Energy (Thermally Limited) ^②	240	mJ
E _{AS} (tested)	Single Pulse Avalanche Energy Tested Value ⑦	480	
I _{AR}	Avalanche Current ①	See Fig. 12a, 12b, 15, 16	Α
E _{AR}	Repetitive Avalanche Energy ①		mJ
TJ	Operating Junction and	-55 to + 175	
T _{STG}	Storage Temperature Range		°C
	Soldering Temperature, for 10 seconds (1.6mm from case)	300	1

Thermal Resistance

	Parameter	Тур.	Max.	Units			
$R_{\theta JC}$	Junction-to-Case ®		1.09				
$R_{\theta JA}$	Junction-to-Ambient (PCB Mount)®		50	°C/W			
$R_{\theta JA}$	Junction-to-Ambient		110				

HEXFET® is a registered trademark of International Rectifier.

^{*}Qualification standards can be found at http://www.irf.com/

Static Electrical Characteristics @ T_J = 25°C (unless otherwise specified)

	Parameter	Min.	Тур.	Max.	Units	Conditions
$V_{(BR)DSS}$	Drain-to-Source Breakdown Voltage	40			V	$V_{GS} = 0V, I_D = 250\mu A$
$\Delta V_{(BR)DSS}/\Delta T_J$	Breakdown Voltage Temp. Coefficient		0.041		V/°C	Reference to 25°C, I _D = 1mA
R _{DS(on)}	Static Drain-to-Source On-Resistance		7.8	9.2	mΩ	V _{GS} = 10V, I _D = 30A ⊕**
$V_{GS(th)}$	Gate Threshold Voltage	2.0		4.0	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$
gfs	Forward Transconductance	40			S	$V_{DS} = 10V, I_D = 30A^{**}$
I _{DSS}	Drain-to-Source Leakage Current			20	μΑ	$V_{DS} = 40V, V_{GS} = 0V$
			_	250		$V_{DS} = 40V, V_{GS} = 0V, T_{J} = 125^{\circ}C$
I _{GSS}	Gate-to-Source Forward Leakage			200	nA	$V_{GS} = 20V$
	Gate-to-Source Reverse Leakage			-200		$V_{GS} = -20V$

Dynamic Electrical Characteristics @ T_J = 25°C (unless otherwise specified)

	Parameter	Min.	Тур.	Max.	Units	Conditions
Q_g	Total Gate Charge		48	71		I _D = 30A **
Q_{gs}	Gate-to-Source Charge		12	18	nC	$V_{DS} = 32V$
Q_{gd}	Gate-to-Drain ("Miller") Charge		13	20		V _{GS} = 10V ⊕
t _{d(on)}	Turn-On Delay Time		11			$V_{DD} = 20V$
t _r	Rise Time		53			I _D = 30A **
t _{d(off)}	Turn-Off Delay Time		36		ns	$R_G = 6.8\Omega$
t _f	Fall Time		22			V _{GS} = 10V ⊕
L _D	Internal Drain Inductance		4.5			Between lead,
					nΗ	6mm (0.25in.)
L _S	Internal Source Inductance		7.5			from package
						and center of die contact
C _{iss}	Input Capacitance		2150			$V_{GS} = 0V$
Coss	Output Capacitance		580		pF	$V_{DS} = 25V$
C _{rss}	Reverse Transfer Capacitance		46			f = 1.0MHz, See Fig. 5
C _{oss}	Output Capacitance		2830			$V_{GS} = 0V, V_{DS} = 1.0V, f = 1.0MHz$
Coss	Output Capacitance		510			$V_{GS} = 0V, V_{DS} = 32V, f = 1.0MHz$
C _{oss} eff.	Effective Output Capacitance (5)		870			$V_{GS} = 0V$, $V_{DS} = 0V$ to $32V$

Diode Characteristics

Diode onaracteristics						
	Parameter	Min.	Тур.	Max.	Units	Conditions
I _S	Continuous Source Current			87®		MOSFET symbol
	(Body Diode)				Α	showing the
I _{SM}	Pulsed Source Current			350		integral reverse
	(Body Diode) ①					p-n junction diode.
V_{SD}	Diode Forward Voltage			1.3	V	$T_J = 25^{\circ}C$, $I_S = 30A^{**}$, $V_{GS} = 0V$ @
t _{rr}	Reverse Recovery Time		53	80	ns	$T_J = 25^{\circ}C$, $I_F = 30A^{**}$, $V_{DD} = 20V$
Q _{rr}	Reverse Recovery Charge		86	130	nC	di/dt = 100A/μs ^④
t _{on}	Forward Turn-On Time	Intrinsio	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)			

Notes:

- Repetitive rating; pulse width limited by max. junction temperature. (See fig. 11).
- ② Limited by T_{Jmax} , starting $T_J = 25^{\circ}C$, L = 0.52mH, $R_G = 25\Omega$, $I_{AS} = 30A$, $V_{GS} = 10V$. Part not recommended for use above this
- $\label{eq:loss_def} \begin{tabular}{ll} $ I_{SD} \leq 30A, \ di/dt \leq 170A/\mu s, \ V_{DD} \leq V_{(BR)DSS}, \\ $ T_{J} \leq 175^{\circ}C. \end{tabular}$
- 4 Pulse width \leq 1.0ms; duty cycle \leq 2%.
- $\mbox{\@ifnextcoloredge}$ Limited by $T_{\mbox{\scriptsize Jmax}}$, see Fig.12a, 12b, 15, 16 for typical repetitive avalanche performance.
- This value determined from sample failure population. 100% tested to this value in production.
- Calculated continuous current based on maximum allowable junction temperature. Package limitation current is 56A.
- When mounted on 1" square PCB (FR-4 or G-10 Material). For recommended footprint and soldering techniques refer to application note #AN-994.
- $^{\circledR}$ R $_{\theta}$ is measured at T $_{J}$ of approximately 90°C.
- ** All AC and DC test conditions based on former package limited current of 30A.

Qualification Information[†]

		Automotive (per AEC-Q101) ††			
Qualification	n Level	Comments: This part number(s) passed Automotive qualification. IR's Industrial and Consumer qualification level is granted by extension of the higher Automotive level.			
Moisture Sensitivity Level		D-Pak	MSL1		
Machine Model		Class M4 (+/- 500V) ^{†††} AEC-Q101-002			
ESD	Human Body Model	lodel Class H1C (+/- 1500V) ^{†††} AEC-Q101-001			
	Charged Device Model	Class C5 (+/- 2000V) ^{†††} AEC-Q101-005			
RoHS Compliant Yes			Yes		

- † Qualification standards can be found at International Rectifier's web site: http://www.irf.com/
- †† Exceptions (if any) to AEC-Q101 requirements are noted in the qualification report.
- ††† Highest passing voltage.

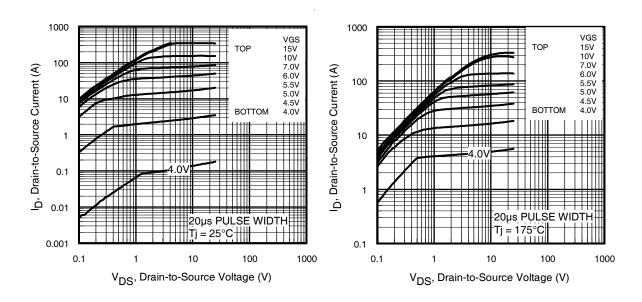


Fig 1. Typical Output Characteristics

Fig 2. Typical Output Characteristics

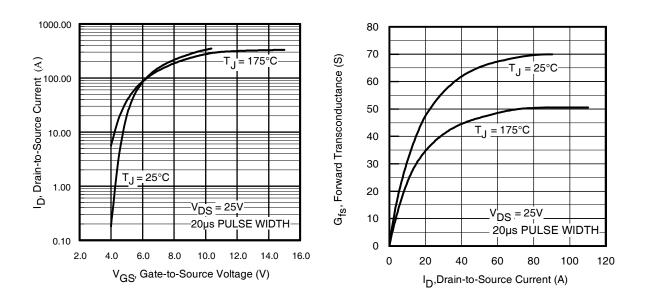
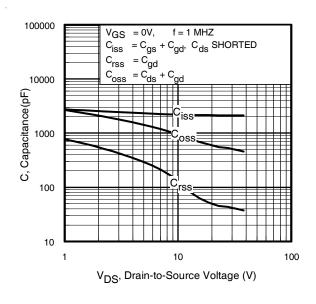


Fig 3. Typical Transfer Characteristics

Fig 4. Typical Forward Transconductance Vs. Drain Current



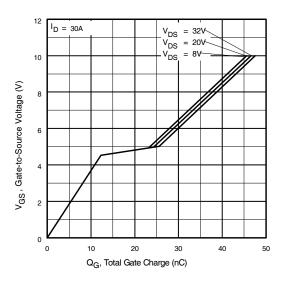
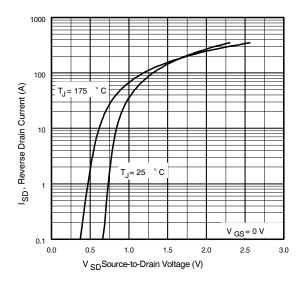


Fig 5. Typical Capacitance Vs. Drain-to-Source Voltage

Fig 6. Typical Gate Charge Vs. Gate-to-Source Voltage



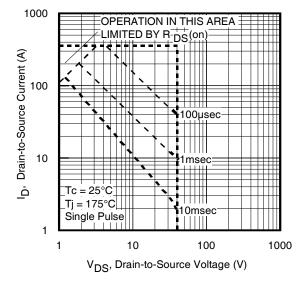
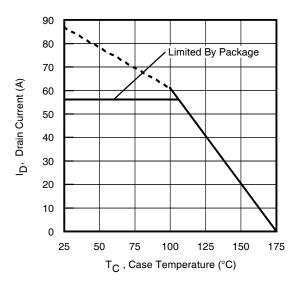


Fig 7. Typical Source-Drain Diode Forward Voltage

Fig 8. Maximum Safe Operating Area



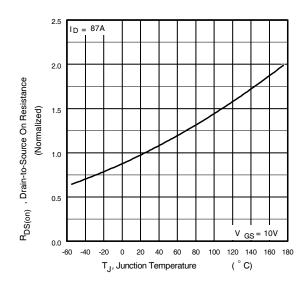


Fig 9. Maximum Drain Current Vs. Case Temperature

Fig 10. Normalized On-Resistance Vs. Temperature

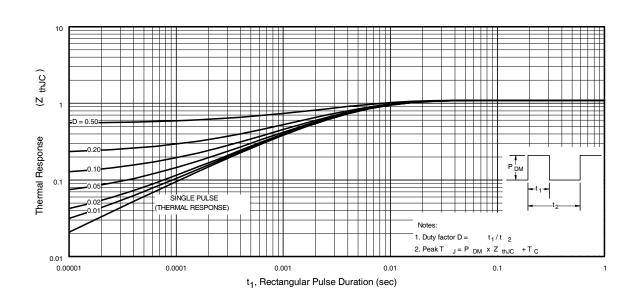


Fig 11. Maximum Effective Transient Thermal Impedance, Junction-to-Case

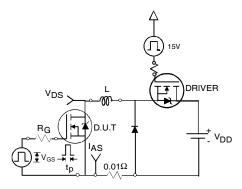


Fig 12a. Unclamped Inductive Test Circuit

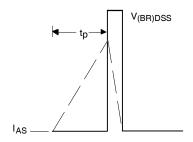


Fig 12b. Unclamped Inductive Waveforms

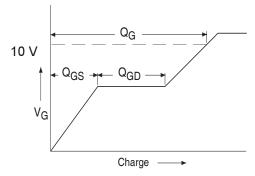
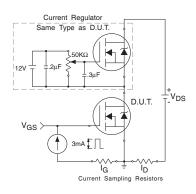


Fig 13a. Basic Gate Charge Waveform



500 I_D TOP 12A 21A 400 воттом 30A E_{AS} , Single Pulse Avalanche Energy (mJ) 300 200 100 25 75 125 150 175 100 Starting Tj, Junction Temperature (°C)

Fig 12c. Maximum Avalanche Energy Vs. Drain Current

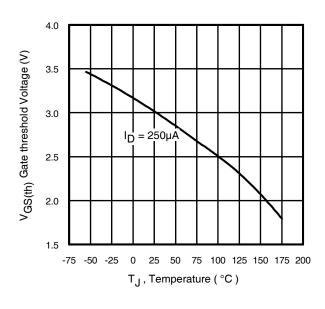


Fig 14. Threshold Voltage Vs. Temperature

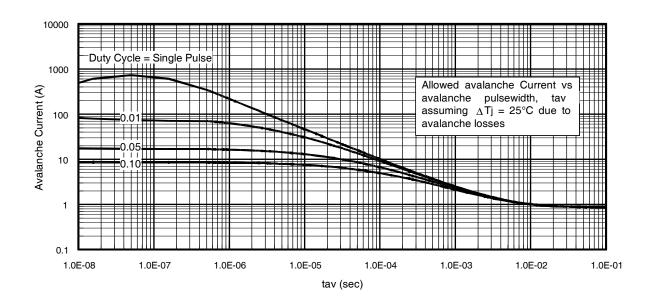
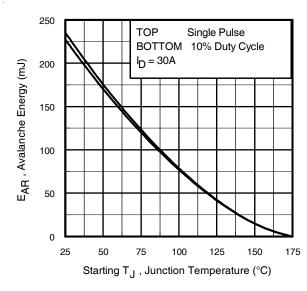


Fig 15. Typical Avalanche Current Vs. Pulsewidth



Notes on Repetitive Avalanche Curves, Figures 15, 16: (For further info, see AN-1005 at www.irf.com)

- Avalanche failures assumption:
 - Purely a thermal phenomenon and failure occurs at a temperature far in excess of T_{jmax} . This is validated for every part type.
- Safe operation in Avalanche is allowed as long asT_{jmax} is not exceeded.
- 3. Equation below based on circuit and waveforms shown in Figures 12a, 12b.
- 4. P_{D (ave)} = Average power dissipation per single avalanche pulse.
- BV = Rated breakdown voltage (1.3 factor accounts for voltage increase during avalanche).
- 6. I_{av} = Allowable avalanche current.
- 7. ΔT = Allowable rise in junction temperature, not to exceed T_{jmax} (assumed as 25°C in Figure 15, 16).
- t_{av} = Average time in avalanche.
- D = Duty cycle in avalanche = $t_{av} \cdot f$
- $Z_{thJC}(D, t_{av})$ = Transient thermal resistance, see figure 11)

$$\begin{split} P_{D \; (ave)} &= 1/2 \; (\; 1.3 \cdot \text{BV} \cdot I_{av}) = \triangle T / \; Z_{thJC} \\ I_{av} &= 2\triangle T / \; [1.3 \cdot \text{BV} \cdot Z_{th}] \\ E_{AS \; (AR)} &= P_{D \; (ave)} \cdot t_{av} \end{split}$$

Fig 16. Maximum Avalanche Energy Vs. Temperature

8

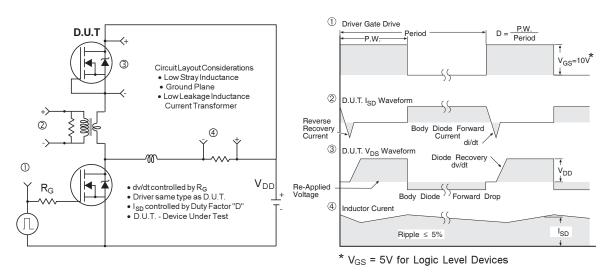


Fig 17. Peak Diode Recovery dv/dt Test Circuit for N-Channel HEXFET® Power MOSFETs

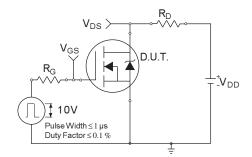


Fig 18a. Switching Time Test Circuit

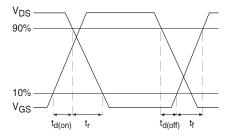
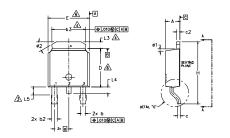
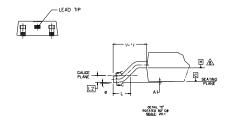


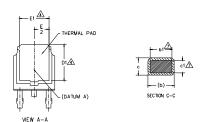
Fig 18b. Switching Time Waveforms

D-Pak (TO-252AA) Package Outline

Dimensions are shown in millimeters (inches)







- 1.- DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994
- 2.- DIMENSION ARE SHOWN IN INCHES [MILLIMETERS].

 LEAD DIMENSION UNCONTROLLED IN L5.
- A- DIMENSION D1, E1, L3 & 63 ESTABLISH A MINIMUM MOUNTING SURFACE FOR THERMAL PAD.
- SECTION C-C DIMENSIONS APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN .005 AND 0.10 [0.13 AND 0.25] FROM THE LEAD TIP.
- DIMENSION D & E DO NOT INCLUDE MOLD FLASH, MOLD FLASH SHALL NOT EXCEED .005 [0.13] PER SIDE. THESE DIMENSIONS ARE MEASURED AT THE OUTMOST EXTREMES OF THE PLASTIC BODY.
- DIMENSION b1 & c1 APPLIED TO BASE METAL ONLY.

 DATUM A & B TO BE DETERMINED AT DATUM PLANE H.
- 9.- OUTLINE CONFORMS TO JEDEC OUTLINE TO-252AA.

S Y			Ŋ		
M B O	MILLIM	ETERS	INC	O T	
O L	MIN.	MAX.	MIN.	MAX.	Ė
Α	2.18	2.39	.086	.094	
A1	-	0.13	-	.005	
b	0,64	0,89	.025	.035	
ь1	0.65	0.79	.025	.031	7
b2	0.76	1,14	.030	.045	
b3	4.95	5.46	.195	.215	4
С	0.46	0.61	.018	.024	
c1	0.41	0.56	.016	.022	7
c2	0.46	0,89	.018	.035	
D	5.97	6.22	.235	.245	6
D1	5.21	-	.205	-	4
Ε	6.35	6.73	.250	.265	6
E1	4.32	-	.170	-	4
e	2.29	BSC	.090	BSC	
н	9,40	10,41	.370	,410	
L	1,40	1.78	.055	.070	
L1	2.74	BSC	.108	REF.	
L2	0.51	BSC	.020	BSC	
L3	0.89	1.27	.035	.050	4
L4	-	1.02	-	.040	
L5	1,14	1.52	.045	.060	3
ø	0.	10*	0.	10*	
ø1	0.	15*	0.	15*	
ø2	25*	35*	25*	35*	

LEAD ASSIGNMENTS

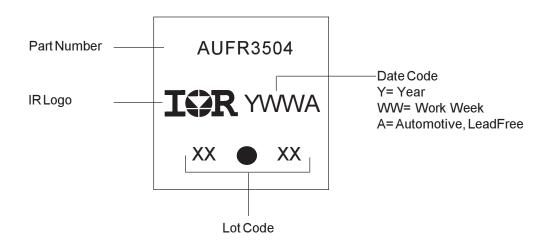
HEXFET

- 1.- GATE 2.- DRAIN 3.- SOURCE 4.- DRAIN

IGBT & CoPAK

- 1.- GATE
 2.- COLLECTOR
 3.- EMITTER
 4.- COLLECTOR

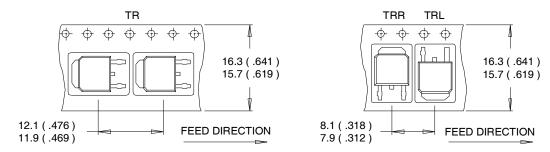
D-Pak Part Marking Information



Note: For the most current drawing please refer to IR website at http://www.irf.com/package/

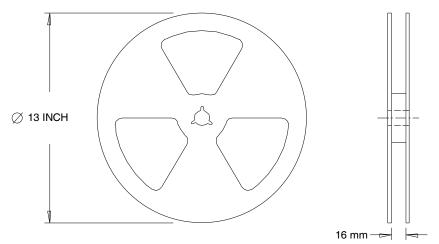
D-Pak (TO-252AA) Tape & Reel Information

Dimensions are shown in millimeters (inches)



NOTES:

- 1. CONTROLLING DIMENSION: MILLIMETER.
- 2. ALL DIMENSIONS ARE SHOWN IN MILLIMETERS (INCHES).
- 3. OUTLINE CONFORMS TO EIA-481 & EIA-541.



NOTES:

1. OUTLINE CONFORMS TO EIA-481.

Ordering Information

Base part number	Package Type	Standard Pack		Complete Part Number
		Form	Quantity	
AUIRFR3504	Dpak	Tube	75	AUIRFR3504
		Tape and Reel	2000	AUIRFR3504TR
		Tape and Reel Left	3000	AUIRFR3504TRL
		Tape and Reel Right	3000	AUIRFR3504TRR

AUIRFR3504

IMPORTANT NOTICE

Unless specifically designated for the automotive market, International Rectifier Corporation and its subsidiaries (IR) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or services without notice. Part numbers designated with the "AU" prefix follow automotive industry and / or customer specific requirements with regards to product discontinuance and process change notification. All products are sold subject to IR's terms and conditions of sale supplied at the time of order acknowledgment.

IR warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with IR's standard warranty. Testing and other quality control techniques are used to the extent IR deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

IR assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using IR components. To minimize the risks with customer products and applications, customers should provide adequate design and operating safeguards.

Reproduction of IR information in IR data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alterations is an unfair and deceptive business practice. IR is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of IR products or serviced with statements different from or beyond the parameters stated by IR for that product or service voids all express and any implied warranties for the associated IR product or service and is an unfair and deceptive business practice. IR is not responsible or liable for any such statements.

IR products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or in other applications intended to support or sustain life, or in any other application in which the failure of the IR product could create a situation where personal injury or death may occur. Should Buyer purchase or use IR products for any such unintended or unauthorized application, Buyer shall indemnify and hold International Rectifier and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that IR was negligent regarding the design or manufacture of the product.

Only products certified as military grade by the Defense Logistics Agency (DLA) of the US Department of Defense, are designed and manufactured to meet DLA military specifications required by certain military, aerospace or other applications. Buyers acknowledge and agree that any use of IR products not certified by DLA as military-grade, in applications requiring military grade products, is solely at the Buyer's own risk and that they are solely responsible for compliance with all legal and regulatory requirements in connection with such use.

IR products are neither designed nor intended for use in automotive applications or environments unless the specific IR products are designated by IR as compliant with ISO/TS 16949 requirements and bear a part number including the designation "AU". Buyers acknowledge and agree that, if they use any non-designated products in automotive applications, IR will not be responsible for any failure to meet such requirements.

For technical support, please contact IR's Technical Assistance Center http://www.irf.com/technical-info/

WORLDHEADQUARTERS:

101 N. Sepulveda Blvd., El Segundo, California 90245
Tel: (310) 252-7105

AMEYA360 Components Supply Platform

Authorized Distribution Brand:

























Website:

Welcome to visit www.ameya360.com

Contact Us:

> Address:

401 Building No.5, JiuGe Business Center, Lane 2301, Yishan Rd Minhang District, Shanghai , China

> Sales:

Direct +86 (21) 6401-6692

Email amall@ameya360.com

QQ 800077892

Skype ameyasales1 ameyasales2

Customer Service :

Email service@ameya360.com

Partnership :

Tel +86 (21) 64016692-8333

Email mkt@ameya360.com